



Application

Industrial use Biomedical

Property

Wavelength $\lambda = 515 \text{ nm}$ Output Power = 10 mW Package Type = φ 5.6mm

Introduction

Egismos currently markets InGaN-based green laser diodes 515-520nm wavelengths range. The low operating current and high temperature of the laser diodes are achieved through using misoriented substrate and MQW (Strain compensated) active layer. Egismos laser diodes are highly rated in a broad range of applications including, but not limited to, laser pointers, green lasers, blue laser DVD, laser barcode scanners, diode laser equipments, medical instruments and aerospace applications.

Red Laser Diode Key features

Absolute Maximum Rating at Tc=25℃

Items	Symbols	Values	Unit
Operating Current power	P。	10	mW
Reverse Voltage	V_{R}	2	V
Operating Temperature	T_{case}	-10~+60	$^{\circ}\!\mathrm{C}$
Storage Temperature	T_{s}	-40~+85	$^{\circ}\!\mathrm{C}$

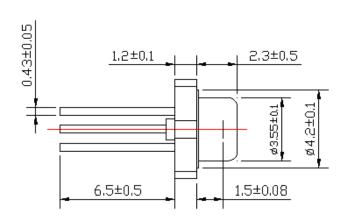


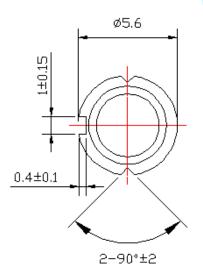


Electrical and Optical Characteristics at Tc=25℃

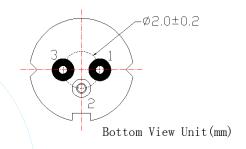
ltem	Symbols	Min	Тур.	Max.	Unit	Condition
Threshold Current	I_{th}	-	30	60	mA	-
Operating Current	l _{op}	-	60	100	mA	Po=10mW
Operating Voltage	V_{op}	-	6.0	7.0	V	Po=10mW
Peak Wavelength	λр	510	520	530	nm	Po=10mW
Beam Divergence (FWHM)	$\theta_{/\!\!/}$	4	7	11	deg	Po=10mW
Beam Divergence (FWHM)	$ heta$ $^{\perp}$	16	22	25	deg	Po=10mW

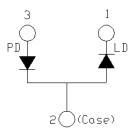
Package Drawing





ELECTRICAL CONNECTION





Specifications are subject to change without notice.







